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FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation ⁶
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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁶
		R. Colombelli, et al.: "Far-Infrared Surface-Plasmon Quantum-Cascade Lasers at 21.5 μm and 24 μm Wavelengths"; Applied Physics Letters, American Institute of Physics. New York, US, vol. 28, no. 18, April 30, 2001, pages 2620-2622, XP001059510, ISSN: 0003-6951, cited in the application page 2620, right hand column, paragraph 2, Figures 1, 2, page 2621, left-hand column, paragraph 2, pages 2622, right-hand column, paragraph 1	
		R. Koehler, et al.: "High Intensity Interminiband Terahertz Emission From Chirped Superlattices" Applied Physics Letters, American Institute of Physics. New York, US, vol. 80, no. 11, March 18, 2002, pages 1867-1869, XP001108440, ISSN: 0003-6951, abstract page 1867, left-hand column-right-hand column	
		R. Koehler, et al.: "Terahertz Semiconductor-Heterostructure Laser" Nature, Macmillan Journals Ltd., London, GB, Vol. 417, May 9, 2002, pages 156-159, XP001147572, ISSN: 0028-0836	
		M. Rocchat, et al.: "Low-Threshold Terahertz Quantum-Cascade Lasers" Applied Physics Letters, American Institute of Physics. New York, US, vol. 81, no. 8, August 19, 2002, pages 1381-1383, XP001142480, ISSN: 0003-6951	
		C. Sirtori, et al.: "Low-loss Al-Free Waveguides for Unipolar Semiconductor Lasers" Applied Physics Letters, American Institute of Physics. New York, US, vol. 75, no. 25, December 20, 1999, pages 3911-3913, XP000902551, ISSN: 0003-6951, page 3911, right-hand column; figure 1 and 2, page 36912, left-hand column, line 1-line 13, page 3912, right-hand column, line 1-6, page 3913, left-hand column, paragraph 3	

Date Considered

¹ Applicant's unique citation designation number (optional). ² See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or in the comment box of this document. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to indicate here if English language Translation is attached.